

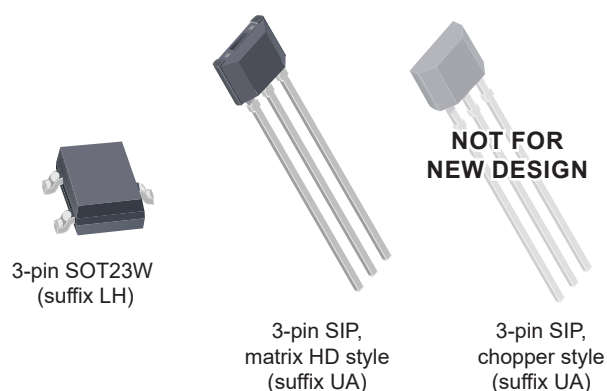
## Chopper-Stabilized Omnipolar Hall-Effect Switch

### FEATURES AND BENEFITS

- AEC-Q100 automotive qualified
- Omnipolar operation
- Low switchpoint drift
- Superior temperature stability
- Insensitive to physical stress
- Reverse-battery protection
- Robust EMC capability
- Robust ESD protection

### PACKAGES:

*Not to scale*



### DESCRIPTION

The A1126 integrated circuit is an omnipolar, ultrasensitive Hall-effect switch with a digital output. This device has an integrated regulator permitting operation to 24 V.

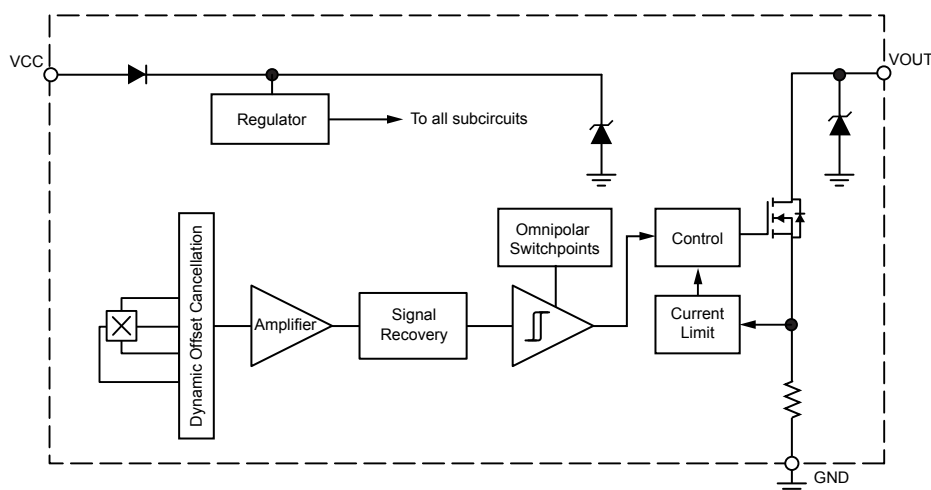
This device is especially suited for operation through extended temperature ranges, up to 150°C. Superior high-temperature performance is made possible through a dynamic offset cancellation technique, which reduces the residual offset voltage normally caused by device overmolding, temperature excursions, and thermal stress.

The A1126 Hall-effect switch includes the following on a single silicon chip: voltage regulator, Hall-voltage generator, small-signal amplifier, chopper stabilization, Schmitt trigger, and a short-circuit-protected open-drain output. Advanced BiCMOS wafer fabrication processing is used to take advantage of low-voltage requirements, component matching, very low input-offset errors, and small component geometries.

The omnipolar operation of the A1126 allows activation with either a north or a south polarity field of sufficient strength. In the absence of a magnetic field, the output is off. This patented magnetic-polarity-independence feature makes this device an excellent replacement for reed switches, with improved ease of manufacturing, because the A1126 does not require

*Continued on the next page...*

### Functional Block Diagram



A1126

Chopper-Stabilized Omnipolar Hall-Effect Switch

DESCRIPTION (CONTINUED)

manufacturers to orient their magnets. These devices allow simple on/off switching in industrial, consumer, and automotive applications.

The A1126 is rated for operation between the ambient temperatures  $-40^{\circ}\text{C}$  to  $150^{\circ}\text{C}$ . The available package styles provide magnetically optimized solutions for most applications. Package LH is an SOT23W,

a miniature low-profile surface-mount package, while package UA is a three-lead ultra-mini SIP for through-hole mounting. Each package is lead (Pb) free, with 100% matte-tin-plated leadframe.

SELECTION GUIDE

Part Number	Packing [1]	Package
A1126LLHLT-T [2]	3,000 pieces per reel	3-pin SOT-23W surface mount
A1126LLHLX-T	10,000 pieces per reel	3-pin SOT-23W surface mount
A1126LUA-T [3]	500 pieces per bag	3-pin ultramini SIP through-hole mount

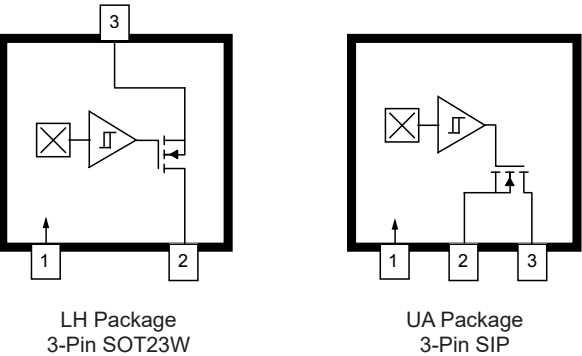


<sup>1</sup> Contact Allegro™ for additional packing options  
<sup>2</sup> Available through authorized Allegro distributors only.  
<sup>3</sup> The chopper-style UA package is not for new design; the matrix HD style UA package is recommended for new designs.

ABSOLUTE MAXIMUM RATINGS

Characteristic	Symbol	Notes	Rating	Unit
Forward Supply Voltage	$V_{CC}$		28	V
Reverse Supply Voltage	$V_{RCC}$		-18	V
Output Off Voltage	$V_{OUT}$		28	V
Reverse Supply Current	$I_{RCC}$		-2	mA
Continuous Output Current	$I_{OUT}$		Internally limited	—
Operating Ambient Temperature	$T_A$	L temperature range	-40 to 150	$^{\circ}\text{C}$
Maximum Junction Temperature	$T_J(\text{max})$		165	$^{\circ}\text{C}$
Storage Temperature	$T_{stg}$		-65 to 170	$^{\circ}\text{C}$

Pinout Diagrams



Terminal List Table

Name	Number		Function
	LH	UA	
VCC	1	1	Connects power supply to chip
VOUT	2	3	Output from circuit
GND	3	2	Ground

**OPERATING CHARACTERISTICS:** Valid through  $T_A$  and  $V_{CC}$  ranges,  $T_J < T_{J(max)}$ ,  $C_{BYP} = 0.1 \mu F$ , unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Unit [1]
<b>ELECTRICAL CHARACTERISTICS</b>						
Supply Voltage	$V_{CC}$	Operating, $T_J < 165^\circ C$	3	—	24	V
Output Leakage Current	$I_{OUTOFF}$	$V_{OUT} = 24 V$ , $B < B_{RPS}$	—	—	10	$\mu A$
Output On Voltage	$V_{OUT(SAT)}$	$I_{OUT} = 20 mA$ , $B > B_{OP}$	—	185	500	mV
Output Current Limit	$I_{OM}$	$B > B_{OP}$	30	—	60	mA
Power-On Time [2][3]	$t_{PO}$		—	—	25	$\mu s$
Chopping Frequency	$f_C$		—	800	—	kHz
Output Rise Time [3][4]	$t_r$	$R_{LOAD} = 820 \Omega$ , $C_S = 20 pF$	—	0.2	2	$\mu s$
Output Fall Time [3][4]	$t_f$	$R_{LOAD} = 820 \Omega$ , $C_S = 20 pF$	—	0.1	2	$\mu s$
Supply Current	$I_{CC(ON)}$	$B > B_{OP}$ , $V_{CC} = 12 V$	—	—	4	mA
	$I_{CC(OFF)}$	$B < B_{RP}$ , $V_{CC} = 12 V$	—	—	4	mA
Supply Zener Clamp Voltage	$V_Z$	$I_{CC} = 6.5 mA$ ; $T_A = 25^\circ C$	28	—	—	V
Supply Zener Current	$I_{ZSUPPLY}$	$V_S = 28 V$	—	—	6.5	mA
<b>MAGNETIC CHARACTERISTICS</b>						
Operate Point	$B_{OPS}$	South pole adjacent to branded face	15	38	55	G
	$B_{OPN}$	North pole adjacent to branded face	−55	−38	−15	G
Release Point	$B_{RPS}$	South pole adjacent to branded face	5	20	50	G
	$B_{RPN}$	North pole adjacent to branded face	−50	−20	−5	G
Hysteresis	$B_{HYS}$	$ B_{OPS} - B_{RPS} $ , $ B_{OPN} - B_{RPN} $	5	—	30	G

<sup>1</sup> 1 G (gauss) = 0.1 mT (millitesla).

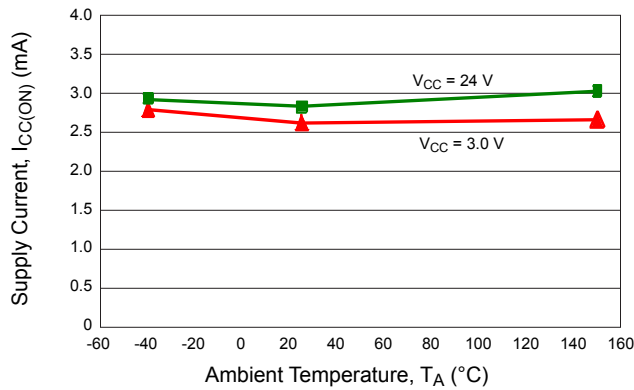
<sup>2</sup>  $B < B_{RP(min)} - 10 G$ ,  $B > B_{OP(max)} + 10 G$ .

<sup>3</sup> Guaranteed by device design and characterization.

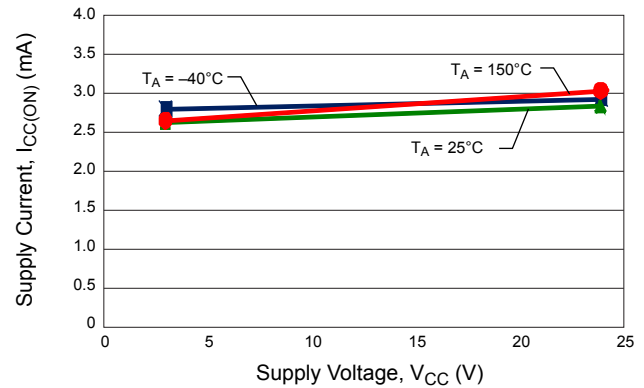
<sup>4</sup>  $C_S$  = oscilloscope probe capacitance.

## Characteristic Performance

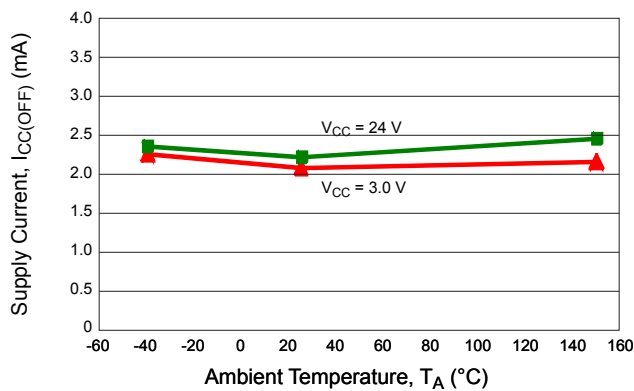
Average Supply Current (On) versus Temperature



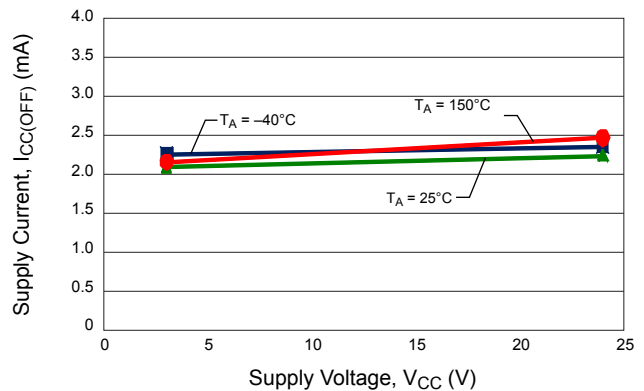
Average Supply Current (On) versus Supply Voltage



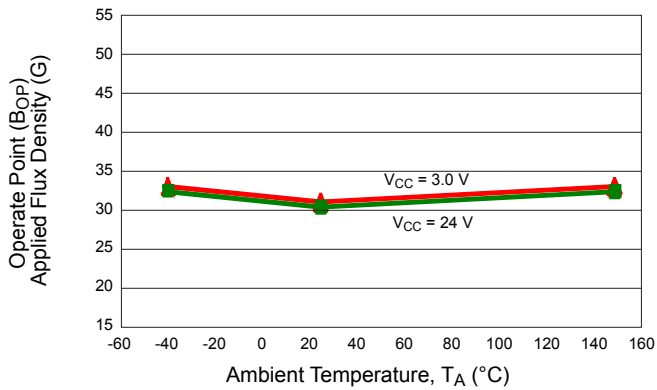
Average Supply Current (Off) versus Temperature



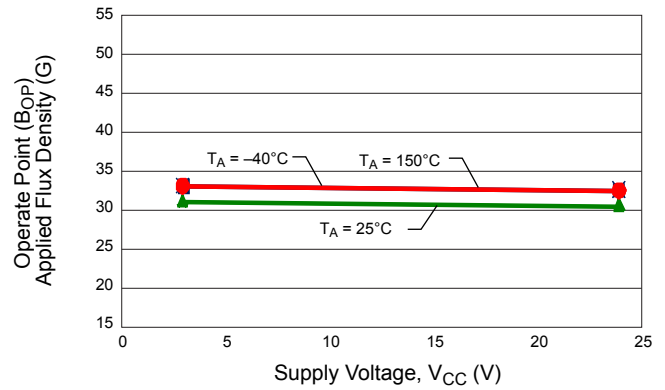
Average Supply Current (Off) versus Supply Voltage



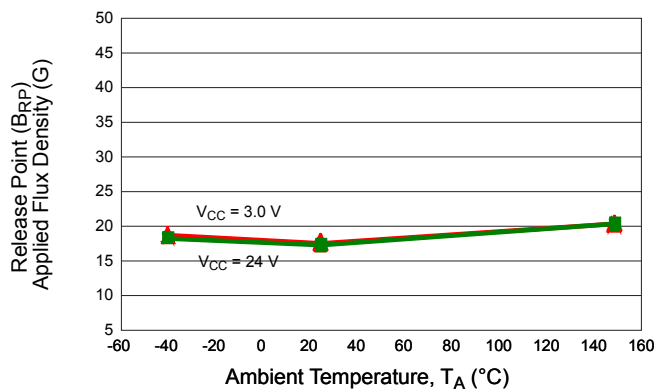
Average Operate Point (South) versus Temperature



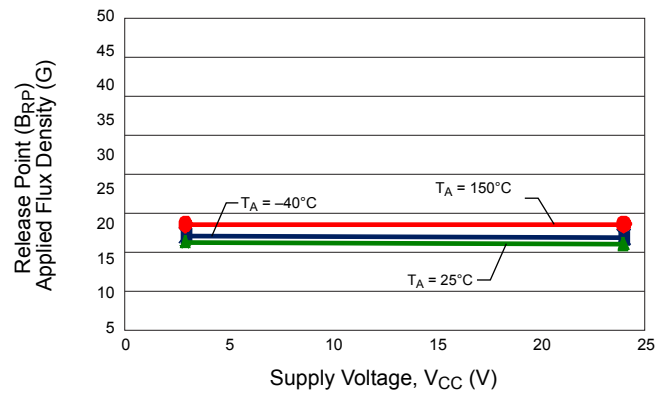
Average Operate Point (South) versus Supply Voltage

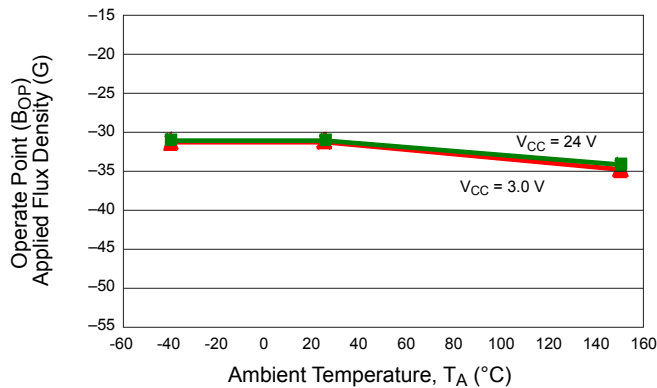
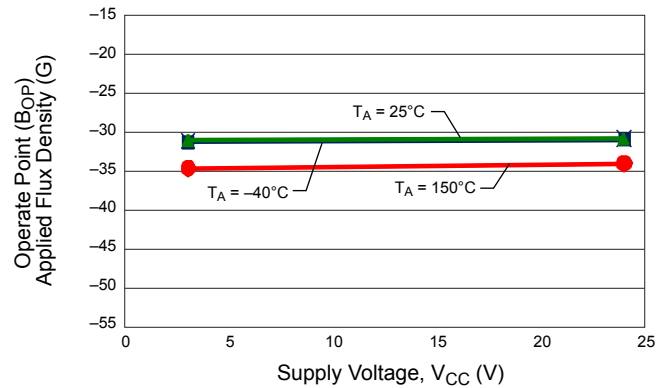
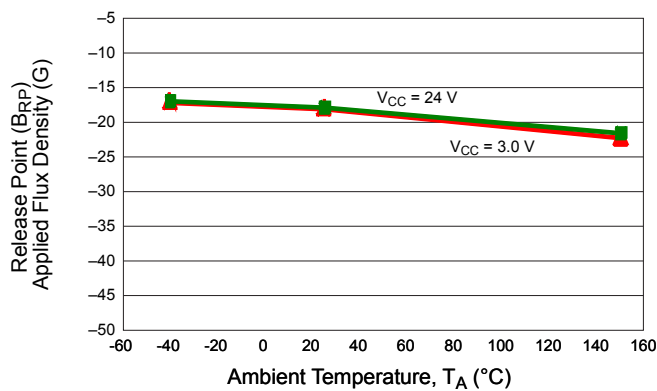
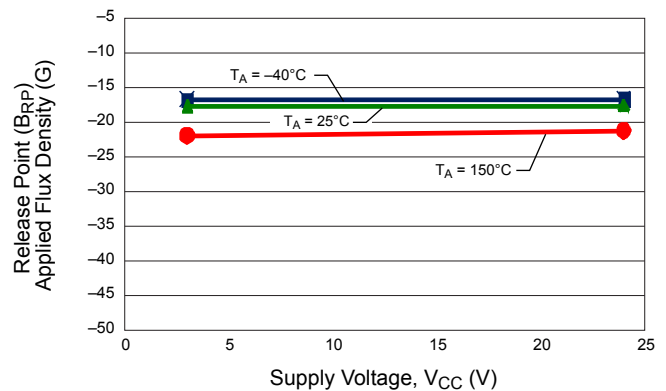


Average Release Point (South) versus Temperature

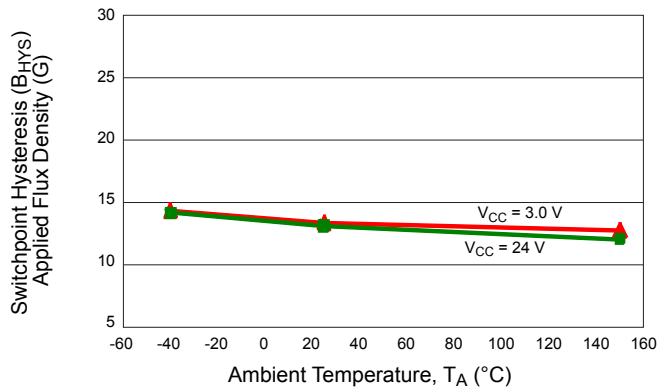


Average Release Point (South) versus Supply Voltage

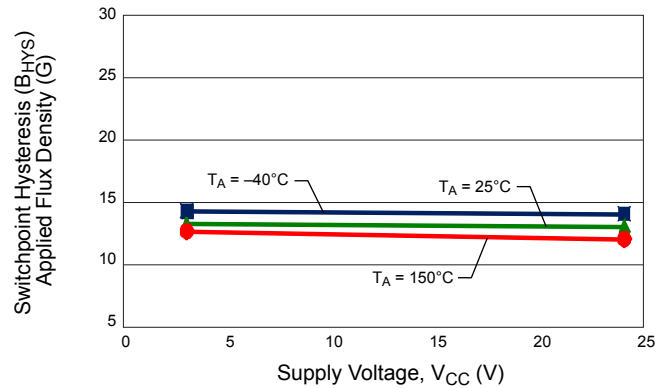


**Average Operate Point (North) versus Temperature****Average Operate Point (North) versus Supply Voltage****Average Release Point (North) versus Temperature****Average Release Point (North) versus Supply Voltage**

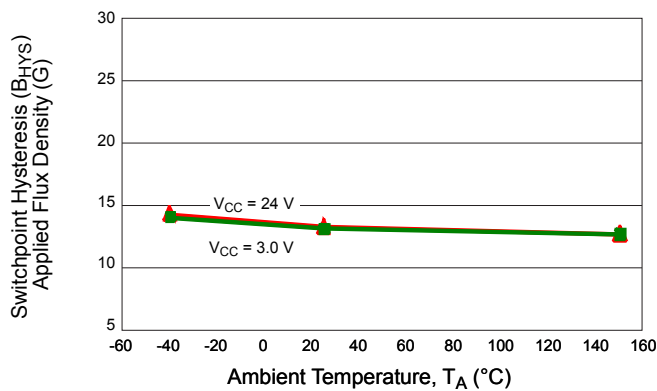
Average Hysteresis (South) versus Temperature



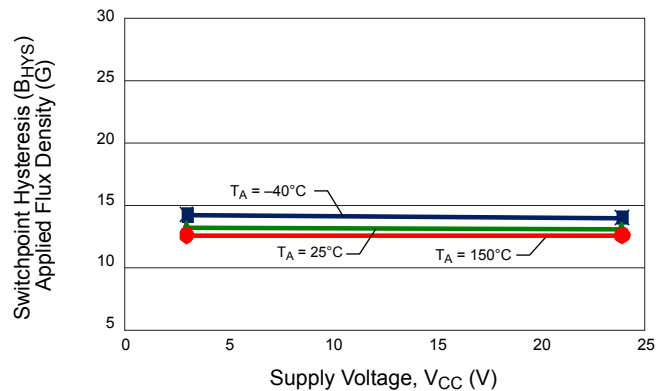
Average Hysteresis (South) versus Supply Voltage



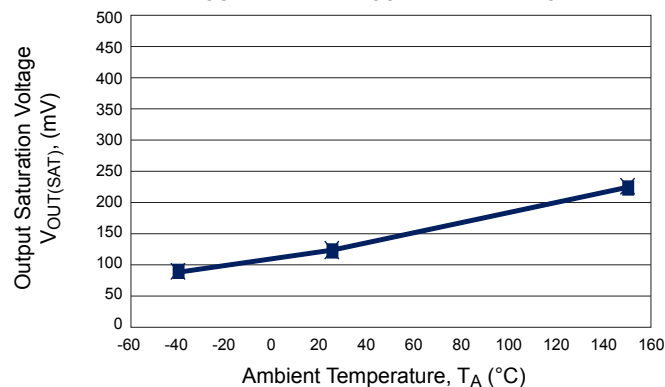
Average Hysteresis (North) versus Temperature



Average Hysteresis (North) versus Supply Voltage



Average Output Saturation Voltage versus Temperature

 $I_{OUT} = 20 \text{ mA}$ ,  $V_{CC} = 12 \text{ V}$ ,  $B > B_{OP}$ 


A1126

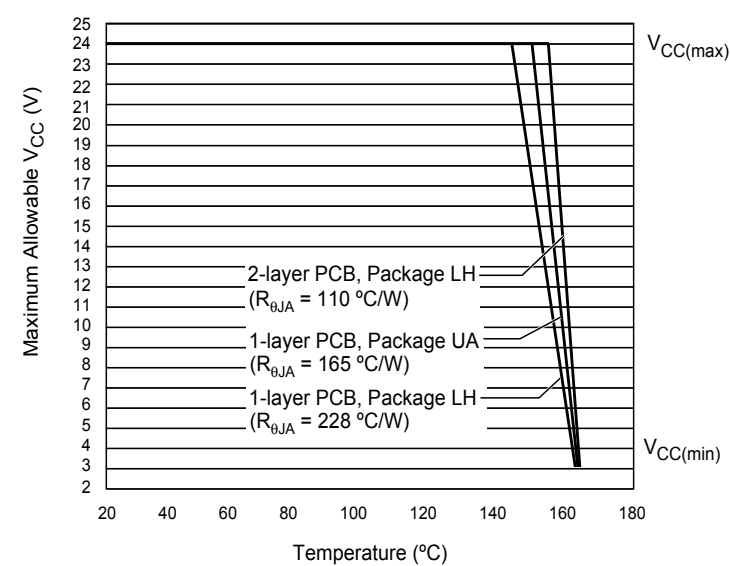
Chopper-Stabilized Omnipolar Hall-Effect Switch

THERMAL CHARACTERISTICS: May require derating at maximum conditions; see application information

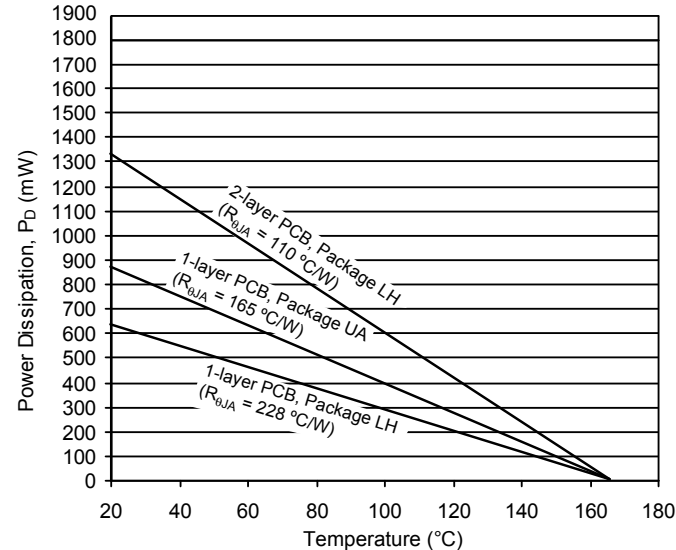
Characteristic	Symbol	Test Conditions*	Value	Units
Package Thermal Resistance	$R_{\theta JA}$	Package LH, 1-layer PCB with copper limited to solder pads	228	°C/W
		Package LH, 2-layer PCB with 0.463 in. <sup>2</sup> of copper area each side connected by thermal vias	110	°C/W
		Package UA, 1-layer PCB with copper limited to solder pads	165	°C/W

\*Additional thermal information available on Allegro Web site.

Power Derating Curve



Power Dissipation versus Ambient Temperature





**FUNCTIONAL DESCRIPTION**

The output of these devices switches low (turns on) when a magnetic field perpendicular to the Hall sensor chip exceeds the operate point threshold,  $B_{OPX}$ . After turn-on, the output voltage is  $V_{OUT(SAT)}$ . The output transistor is capable of sinking current up to the short circuit current limit,  $I_{OM}$ , which is a minimum of 30 mA. When the magnetic field is reduced below the release point,  $B_{RPX}$ , the device output goes high (turns off). The difference in the magnetic operate and release points is the hysteresis,  $B_{HYS}$ , of the device. This built-in hysteresis allows clean switch-

ing of the output even in the presence of external mechanical vibration and electrical noise.

In the case of omnipolar switch devices, removal of the magnetic field results in the device output high (off).

Powering-on the device in the hysteresis range (less than  $B_{OPX}$  and greater than  $B_{RPX}$ ) will allow an indeterminate output state. The correct state is attained after the first excursion beyond  $B_{OPX}$  or  $B_{RPX}$ .

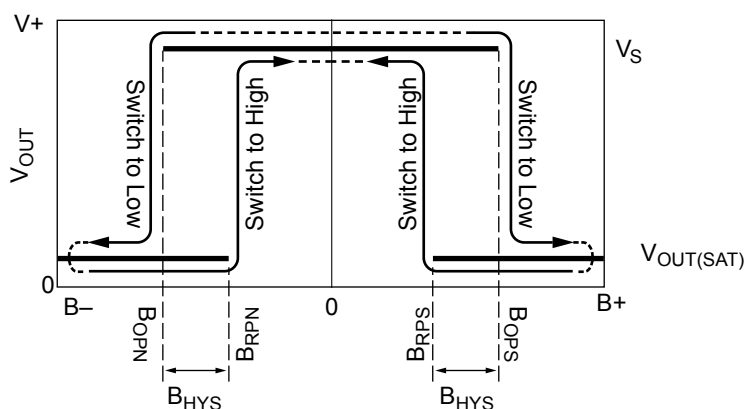


Figure 1. Switching behavior of omnipolar switches. On the horizontal axis, the B+ direction indicates increasing south polarity magnetic field strength, and the B- direction indicates increasing north polarity. This behavior can be exhibited when using a circuit such as that shown in figure 2.

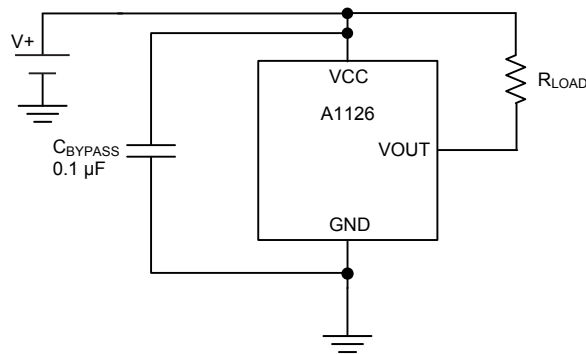
**APPLICATION INFORMATION**

Figure 2. Typical Application Circuit

**Chopper Stabilization Technique**

When using Hall-effect technology, a limiting factor for switchpoint accuracy is the small signal voltage developed across the Hall element. This voltage is disproportionally small relative to the offset that can be produced at the output of the Hall sensor chip. This makes it difficult to process the signal while maintaining an accurate, reliable output over the specified operating temperature and voltage ranges. Chopper stabilization is a unique approach used to minimize Hall offset on the chip. The Allegro technique, namely Dynamic Quadrature Offset Cancellation, removes key sources of the output drift induced by thermal and mechanical stresses. This offset reduction technique is based on a signal modulation-demodulation process. The undesired offset signal is separated from the magnetic field-induced signal in the frequency domain, through modulation. The subsequent demodulation acts as a modulation process for the offset, causing the magnetic field-induced signal to recover its original spectrum at

baseband, while the DC offset becomes a high-frequency signal. The magnetic-sourced signal then can pass through a low-pass filter, while the modulated DC offset is suppressed. The chopper stabilization technique uses a 400 kHz high frequency clock. For demodulation process, a sample-and-hold technique is used, where the sampling is performed at twice the chopper frequency. This high-frequency operation allows a greater sampling rate, which results in higher accuracy and faster signal-processing capability. This approach desensitizes the chip to the effects of thermal and mechanical stresses, and produces devices that have extremely stable quiescent Hall output voltages and precise recoverability after temperature cycling. This technique is made possible through the use of a BiCMOS process, which allows the use of low-offset, low-noise amplifiers in combination with high-density logic integration and sample-and-hold circuits.

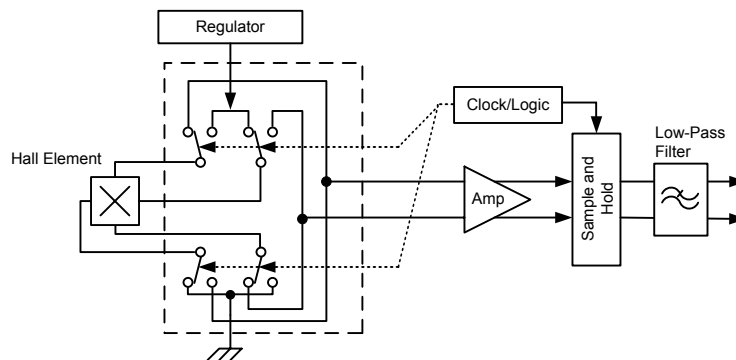


Figure 3. Concept of Chopper Stabilization Technique

## Power Derating

The device must be operated below the maximum junction temperature of the device,  $T_J(\text{max})$ . Under certain combinations of peak conditions, reliable operation may require derating supplied power or improving the heat dissipation properties of the application. This section presents a procedure for correlating factors affecting operating  $T_J$ . (Thermal data is also available on the Allegro MicroSystems Web site.)

The Package Thermal Resistance,  $R_{\theta JA}$ , is a figure of merit summarizing the ability of the application and the device to dissipate heat from the junction (die), through all paths to the ambient air. Its primary component is the Effective Thermal Conductivity,  $K$ , of the printed circuit board, including adjacent devices and traces. Radiation from the die through the device case,  $R_{\theta JC}$ , is relatively small component of  $R_{\theta JA}$ . Ambient air temperature,  $T_A$ , and air motion are significant external factors, damped by overmolding.

The effect of varying power levels (Power Dissipation,  $P_D$ ), can be estimated. The following formulas represent the fundamental relationships used to estimate  $T_J$ , at  $P_D$ .

$$P_D = V_{IN} \times I_{IN} \quad (1)$$

$$\Delta T = P_D \times R_{\theta JA} \quad (2)$$

$$T_J = T_A + \Delta T \quad (3)$$

For example, given common conditions such as:  $T_A = 25^\circ\text{C}$ ,  $V_{IN} = 12\text{ V}$ ,  $I_{IN} = 4\text{ mA}$ , and  $R_{\theta JA} = 140^\circ\text{C/W}$ , then:

$$P_D = V_{IN} \times I_{IN} = 12\text{ V} \times 4\text{ mA} = 48\text{ mW}$$

$$\Delta T = P_D \times R_{\theta JA} = 48\text{ mW} \times 140^\circ\text{C/W} = 7^\circ\text{C}$$

$$T_J = T_A + \Delta T = 25^\circ\text{C} + 7^\circ\text{C} = 32^\circ\text{C}$$

A worst-case estimate,  $P_D(\text{max})$ , represents the maximum allowable power level, without exceeding  $T_J(\text{max})$ , at a selected  $R_{\theta JA}$  and  $T_A$ .

*Example:* Reliability for  $V_{CC}$  at  $T_A = 150^\circ\text{C}$ , package UA, using a single-layer PCB.

Observe the worst-case ratings for the device, specifically:  $R_{\theta JA} = 165^\circ\text{C/W}$ ,  $T_J(\text{max}) = 165^\circ\text{C}$ ,  $V_{CC}(\text{max}) = 24\text{ V}$ , and  $I_{CC}(\text{max}) = 4\text{ mA}$ .

Calculate the maximum allowable power level,  $P_D(\text{max})$ . First, invert equation 3:

$$\Delta T_{\text{max}} = T_J(\text{max}) - T_A = 165^\circ\text{C} - 150^\circ\text{C} = 15^\circ\text{C}$$

This provides the allowable increase to  $T_J$  resulting from internal power dissipation. Then, invert equation 2:

$$P_D(\text{max}) = \Delta T_{\text{max}} \div R_{\theta JA} = 15^\circ\text{C} \div 165^\circ\text{C/W} = 91\text{ mW}$$

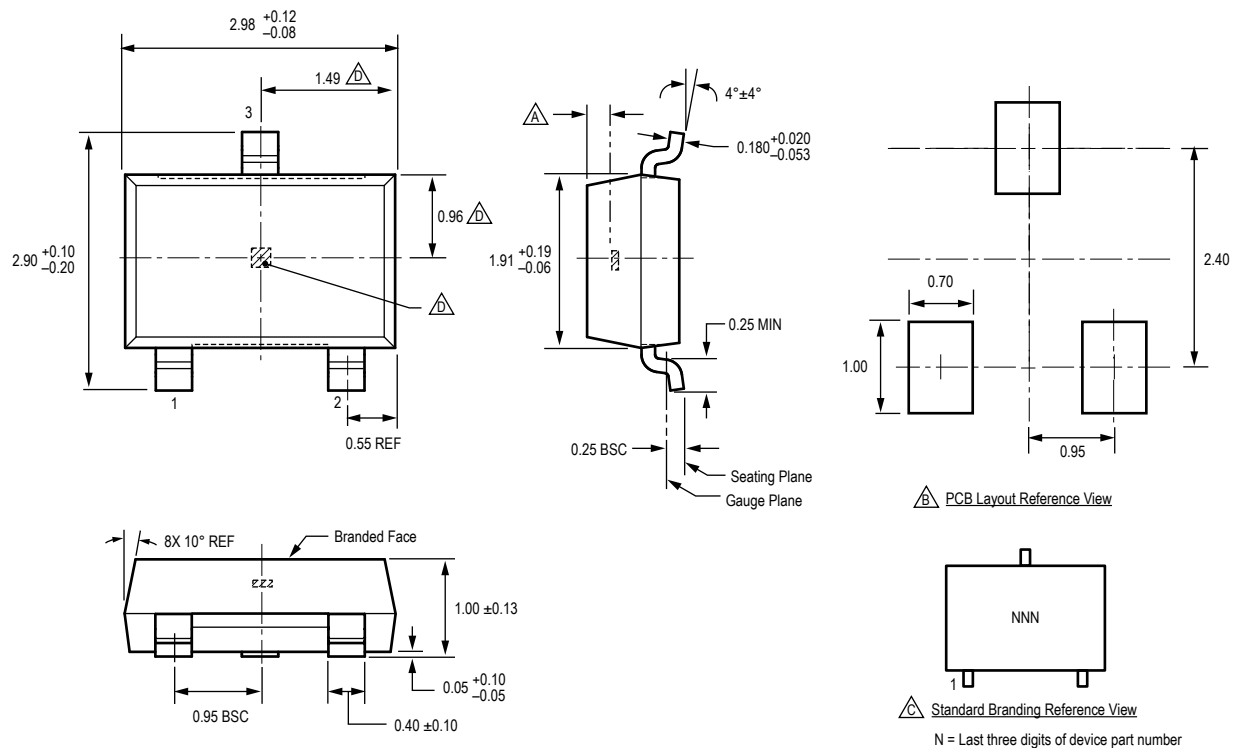
Finally, invert equation 1 with respect to voltage:

$$V_{CC}(\text{est}) = P_D(\text{max}) \div I_{CC}(\text{max}) = 91\text{ mW} \div 4\text{ mA} = 23\text{ V}$$

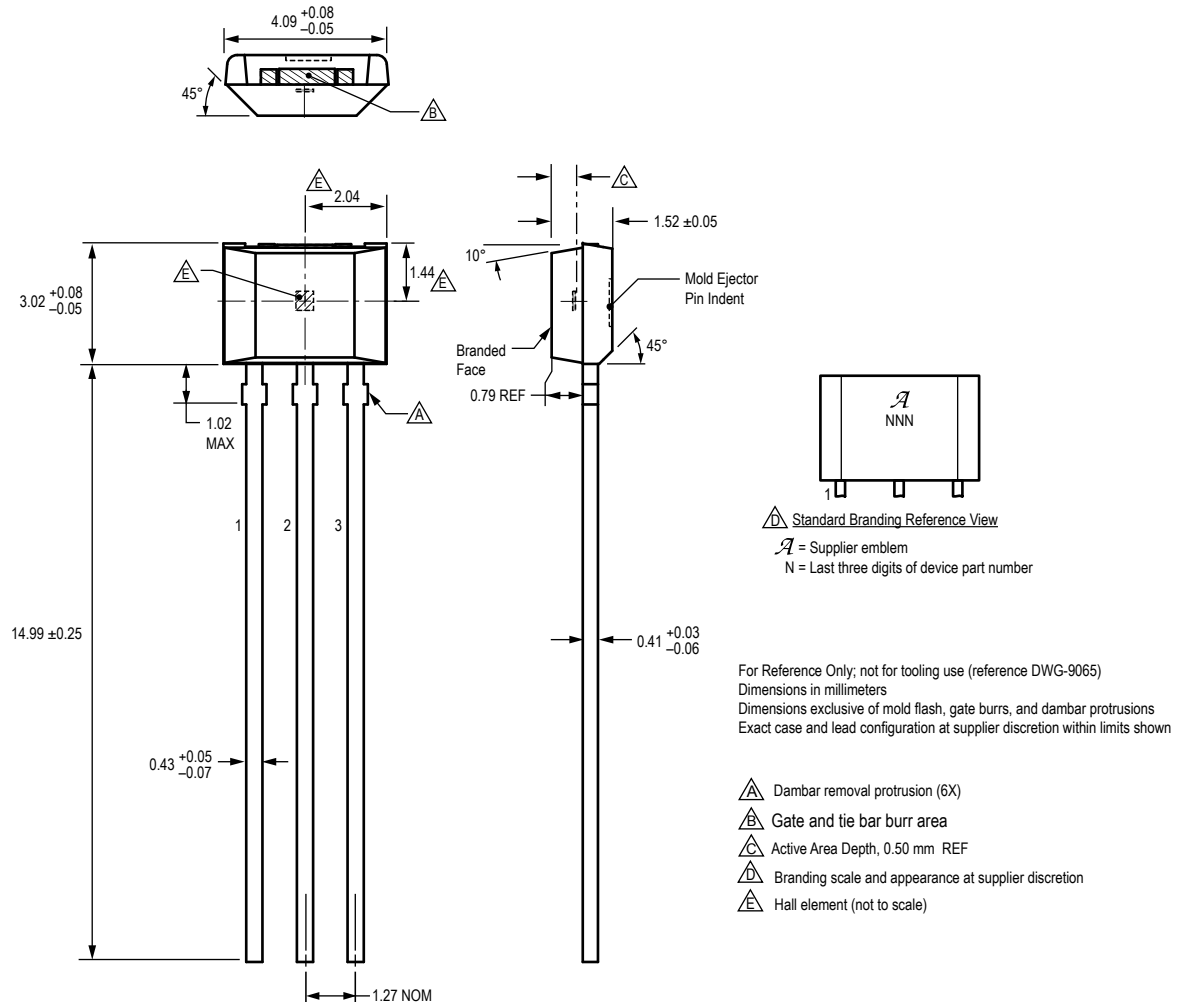
The result indicates that, at  $T_A$ , the application and device can dissipate adequate amounts of heat at voltages  $\leq V_{CC}(\text{est})$ .

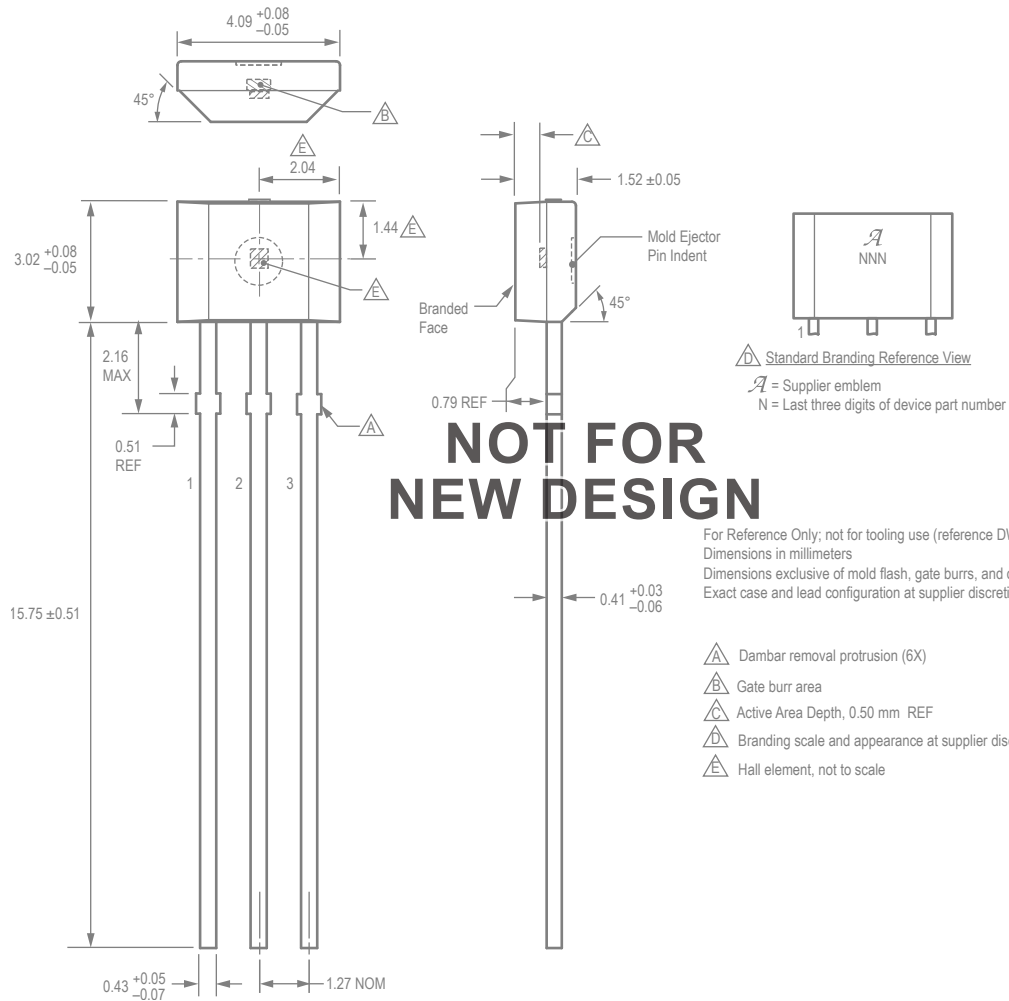
Compare  $V_{CC}(\text{est})$  to  $V_{CC}(\text{max})$ . If  $V_{CC}(\text{est}) \leq V_{CC}(\text{max})$ , then reliable operation between  $V_{CC}(\text{est})$  and  $V_{CC}(\text{max})$  requires enhanced  $R_{\theta JA}$ . If  $V_{CC}(\text{est}) \geq V_{CC}(\text{max})$ , then operation between  $V_{CC}(\text{est})$  and  $V_{CC}(\text{max})$  is reliable under these conditions.

## Package LH, 3-Pin SOT23W



## Package UA, 3-Pin SIP, Matrix Style



**Package UA, 3-Pin SIP, Chopper Style**

**Revision History**

Number	Date	Description
1	September 16, 2013	Update UA package drawing
2	September 21, 2015	Added AEC-Q100 qualification under Features and Benefits
3	October 28, 2016	Chopper-style UA package designated as not for new design

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